High Speed PWM Controller

FEATURES

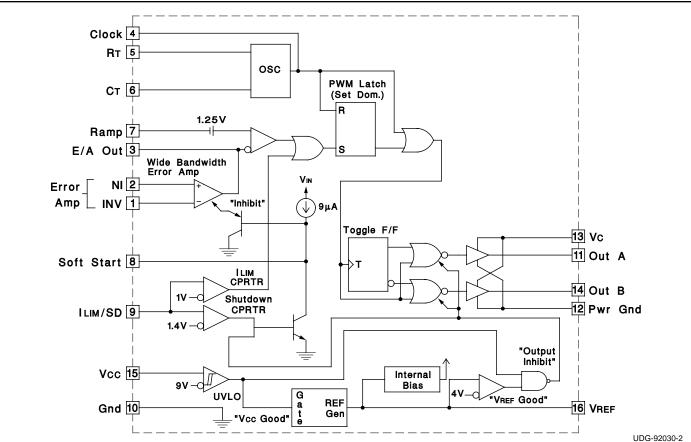
- Compatible with Voltage or Current Mode Topologies
- Practical Operation Switching Frequencies to 1MHz
- 50ns Propagation Delay to Output
- High Current Dual Totem Pole Outputs (1.5A Peak)
- Wide Bandwidth Error Amplifier
- Fully Latched Logic with Double Pulse Suppression
- Pulse-by-Pulse Current Limiting
- Soft Start / Max. Duty Cycle Control
- Under-Voltage Lockout with Hysteresis
- Low Start Up Current (1.1mA)

DESCRIPTION

The UC1825 family of PWM control ICs is optimized for high frequency switched mode power supply applications. Particular care was given to minimizing propagation delays through the comparators and logic circuitry while maximizing bandwidth and slew rate of the error amplifier. This controller is designed for use in either current-mode or voltage mode systems with the capability for input voltage feed-forward.

Protection circuitry includes a current limit comparator with a 1V threshold, a TTL compatible shutdown port, and a soft start pin which will double as a maximum duty cycle clamp. The logic is fully latched to provide jitter free operation and prohibit multiple pulses at an output. An under-voltage lockout section with 800mV of hysteresis assures low start up current. During under-voltage lockout, the outputs are high impedance.

These devices feature totem pole outputs designed to source and sink high peak currents from capacitive loads, such as the gate of a power MOSFET. The on state is designed as a high level.



BLOCK DIAGRAM

ABSOLUTE MAXIMUM		CONNECTION DIAGRA	MS	UC382
Supply Voltage (Pins 13, 15) Output Current, Source or Sink (DC Pulse (0.5 s)	(Pins 11, 14)	DIL-16 (Top View) J or N Package	$\overline{}$	
Analog Inputs		INV 1	16 VREF 5.1V	
(Pins 1, 2, 7)		NI 2	15 Vcc	
(Pin 8, 9)		E/A Out 3	14 Out B	
Error Amplifier Output Current (Pin 4)		Clock 4	13 Vc	
Soft Start Sink Current (Pin 8) .				
Oscillator Charging Current (Pin		RT 5	12 Pwr Gnd	
Power Dissipation		Ст 6	11 Out A	
Storage Temperature Range		Ramp 7	10 Gnd	
Lead Temperature (Soldering, 1		Soft Start 8	9 ILIM/SD	
Note 1: All voltages are with res				
rents are positive into, negative o	out of part; pin numbers refer to			
DIL-16 package.	ted Circuit Databook for thermal		PACKAGE PIN FU	INCTION
imitations and considerations of		PLCC-20 & LCC-20	FUNCTION	PIN
initiatione and conclusionations of	paoliago.			
		(Top View)	N/C	1
SOIC-16 (Top View)		,	INV	2
SOIC-16 (Top View) DW Package		(Top View) Q & L Packages	INV NI	2 3
SOIC-16 (Top View) DW Package		,	INV NI E/A Out	2 3 4
		,	INV NI E/A Out Clock	2 3 4 5
DW Package		Q & L Packages	INV NI E/A Out Clock N/C	2 3 4 5 6
	16 VREF5.1V	,	INV NI E/A Out Clock N/C RT	2 3 4 5 6 7
DW Package	16 VREF5.1V 16 Vcc	Q & L Packages	INV NI E/A Out Clock N/C	2 3 4 5 6
	16 VREF5.1V	Q & L Packages	INV NI E/A Out Clock N/C RT CT	2 3 4 5 6 7 8
DW Package	16) VREF5.1V 15) Vcc 14) Out B	Q & L Packages 3 2 1 20 19 4 18 5 17	INV NI E/A Out Clock N/C RT CT Ramp	2 3 4 5 6 7 8 9
DW Package INV1 NI2 E/A Out3 Clock4	16 VREF5.1V 15 Vcc 14 Out B 13 Vc	Q & L Packages 3 2 1 20 19 4 18 5 17 6 16	INV NI E/A Out Clock N/C RT CT Ramp Soft Start N/C ILIM/SD	2 3 4 5 6 7 8 9 10 11 12
DW Package	16) VREF5.1V 15) Vcc 14) Out B 13) Vc 12) Pwr Gnd	Q & L Packages 3 2 1 20 19 4 18 5 17 6 16 7 15	INV NI E/A Out Clock N/C RT CT Ramp Soft Start N/C ILIM/SD Gnd	2 3 4 5 6 7 8 9 10 11 12 13
DW Package INV1 NI2 E/A Out3 Clock4	16 VREF5.1V 15 Vcc 14 Out B 13 Vc	Q & L Packages 3 2 1 20 19 4 18 5 17 6 16 7 15 8 14	INV NI E/A Out Clock N/C RT CT Ramp Soft Start N/C ILIM/SD Gnd Out A	2 3 4 5 6 7 8 9 10 11 12 13 14
DW Package	16) VREF5.1V 15) Vcc 14) Out B 13) Vc 12) Pwr Gnd	Q & L Packages 3 2 1 20 19 4 18 5 17 6 16 7 15	INV NI E/A Out Clock N/C RT CT Ramp Soft Start N/C ILIM/SD Gnd Out A Pwr Gnd	2 3 4 5 6 7 8 9 10 11 12 13 14 15
DW Package INV1 NI2 E/A Out3 Clock4 RT5 CT6 Ramp7	16) VREF5.1V 15) Vcc 14) Out B 13) Vc 12) Pwr Gnd 11) Out A	Q & L Packages 3 2 1 20 19 4 18 5 17 6 16 7 15 8 14	INV NI E/A Out Clock N/C RT CT Ramp Soft Start N/C ILIM/SD Gnd Out A Pwr Gnd N/C	$ \begin{array}{c} 2\\ 3\\ 4\\ 5\\ 6\\ 7\\ 8\\ 9\\ 10\\ 11\\ 12\\ 13\\ 14\\ 15\\ 16\\ \end{array} $
DW Package INV1 NI2 E/A Out3 Clock4 RT5 CT6	16) VREF5.1V 15) Vcc 14) Out B 13) Vc 12) Pwr Gnd 11) Out A 10) Gnd	Q & L Packages 3 2 1 20 19 4 18 5 17 6 16 7 15 8 14	INV NI E/A Out Clock N/C RT CT Ramp Soft Start N/C ILIM/SD Gnd Out A Pwr Gnd N/C Vc	$ \begin{array}{c} 2\\ 3\\ 4\\ 5\\ 6\\ 7\\ 8\\ 9\\ 10\\ 11\\ 12\\ 13\\ 14\\ 15\\ 16\\ 17\\ \end{array} $
DW Package INV1 NI2 E/A Out3 Clock4 RT5 CT6 Ramp7	16) VREF5.1V 15) Vcc 14) Out B 13) Vc 12) Pwr Gnd 11) Out A 10) Gnd	Q & L Packages 3 2 1 20 19 4 18 5 17 6 16 7 15 8 14	INV NI E/A Out Clock N/C RT CT Ramp Soft Start N/C ILIM/SD Gnd Out A Pwr Gnd N/C	$ \begin{array}{c} 2\\ 3\\ 4\\ 5\\ 6\\ 7\\ 8\\ 9\\ 10\\ 11\\ 12\\ 13\\ 14\\ 15\\ 16\\ \end{array} $

THERMAL RATINGS TABLE

Package	ΘJA	ΘJC
DIL-16J	80-120	28 ⁽²⁾
DIL-16N	90 ⁽¹⁾	45
PLCC-20	43-75(1)	34
LCC-20	70-80	20 ⁽²⁾
SOIC-16	50-120 ⁽¹⁾	35

(1) Specified Θ_{JA} (junction to ambient) is for devices mounted to $5in^2$ FR4 PC board with one ounce copper where noted. When resistance range is given, lower values are for $5in^2$ aluminum PC board. Test PWB was 0.062in thick and typically used 0.635mm trace widths for power packages and 1.3mm trace widths for non-power packages with 100 x 100 mil probe land area at the end of each trace.

(2) Θ_{JC} data values stated were derived from MIL-STD-1835B. MIL-STD-1835B states that the baseline values shown are worst case (mean +2s) for a 60 x 60mil microcircuit device silicon die and applicable for devices with die sizes up to 14400 square mils. For device die sizes greater than 14400 square mils use the following values; dual-in-line, 11°C/W; flat pack 10°C/W; pin grid array, 10°C/W.

PARAMETERS	TEST CONDITIONS		UC1825 UC2825					
		MIN	TOP	MAX	MIN	TOP	MAX	UNITS
Reference Section								
Output Voltage	$To = 25^{\circ}C$, $Io = 1mA$	5.05	5.10	5.15	5.00	5.10	5.20	V
Line Regulation	10V < Vcc < 30V		2	20		2	20	mV
Load Regulation	1mA < IO < 10mA		5	20		5	20	mV
Temperature Stability*	TMIN < TA < TMAX		0.2	0.4		0.2	0.4	mV/°C
Total Output Variation*	Line, Load, Temperature	5.00		5.20	4.95		5.25	V
Output Noise Voltage*	10Hz < f < 10kHz		50			50		μV
Long Term Stability*	T _J = 125°C, 1000hrs.		5	25		5	25	mV
Short Circuit Current	VREF = 0V	-15	-50	-100	-15	-50	-100	mA
Oscillator Section					•			•
Initial Accuracy*	T _J = 2°C	360	400	440	360	400	440	kHz
Voltage Stability*	10V < Vcc < 30V		0.2	2		0.2	2	%
Temperature Stability*	TMIN < TA < TMAX		5			5		%
Total Variation*	340		460	340		460	kHz	
Oscillator Section (cont.)	· ·	•			•			•
Clock Out High		3.9	4.5		3.9	4.5		V
Clock Out Low			2.3	2.9		2.3	2.9	V
Ramp Peak*		2.6	2.8	3.0	2.6	2.8	3.0	V
Ramp Valley*		0.7	1.0	1.25	0.7	1.0	1.25	V
Ramp Valley to Peak*		1.6	1.8	2.0	1.6	1.8	2.0	V
Error Amplifier Section		•	1					
Input Offset Voltage				10			15	mV
Input Bias Current			0.6	3		0.6	3	μA
Input Offset Current			0.1	1		0.1	1	μΑ
Open Loop Gain	1V < V0 < 4V	60	95		60	95		dB
CMRR	1.5V < Vсм < 5.5V	75	95		75	95		dB
PSRR	10V < Vcc < 30V	85	110		85	110		dB
Output Sink Current	VPIN 3 = 1V	1	2.5		1	2.5		mA
Output Source Current	VPIN 3 = 4V	-0.5	-1.3		-0.5	-1.3		mA
Output High Voltage	IPIN 3 = -0.5mA	4.0	4.7	5.0	4.0	4.7	5.0	V
Output Low Voltage	IPIN 3 = 1mA	0	0.5	1.0	0	0.5	1.0	V
Unity Gain Bandwidth*		3	5.5		3	5.5		MHz
Slew Rate*		6	12		6	12		V/µs

ELECTRICAL CHARACTERISTICS: Unless otherwise stated, these specifications apply for , RT = 3.65k, CT = 1nF, Vcc = 15V, -55°C<Ta<125°C for the UC1825, -40°C<Ta<85°C for the UC2825, and 0°C<Ta<70°C for the UC3825, Ta=To.

PARAMETERS	TEST CONDITIONS		UC1825 UC2825					
		MIN	TOP	MAX	MIN	TOP	MAX	UNITS
PWM Comparator Section								
Pin 7 Bias Current	VPIN 7 = 0V		-1	-5		-1	-5	μA
Duty Cycle Range		0		80	0		85	%
Pin 3 Zero DC Threshold	VPIN 7 = 0V	1.1	1.25		1.1	1.25		V
Delay to Output*			50	80		50	80	ns
Soft-Start Section								
Charge Current	VPIN 8 = 0.5V	3	9	20	3	9	20	μA
Discharge Current	VPIN 8 = 1V	1			1			mA
Current Limit / Shutdown S	ection							
Pin 9 Bias Current	0 < VPIN 9 < 4V			15			10	μA
Current Limit Threshold		0.9	1.0	1.1	0.9	1.0	1.1	V
Shutdown Threshold		1.25	1.40	1.55	1.25	1.40	1.55	V
Delay to Output			50	80		50	80	ns
Output Section					•			-
Output Low Level	IOUT = 20mA		0.25	0.40		0.25	0.40	V
	IOUT = 200mA		1.2	2.2		1.2	2.2	V
Output High Level	IOUT = -20mA	13.0	13.5		13.0	13.5		V
	IOUT = -200mA	12.0	13.0		12.0	13.0		V
Collector Leakage	Vc = 30V		100	500		10	500	μA
Rise/Fall Time*	CL = 1nF		30	60		30	60	ns
Under-Voltage Lockout Sec	tion							-
Start Threshold		8.8	9.2	9.6	8.8	9.2	9.6	V
UVLO Hysteresis		0.4	0.8	1.2	0.4	0.8	1.2	V
Supply Current Section		_			-			-
Start Up Current	Vcc = 8V		1.1	2.5		1.1	2.5	mA
ICC	VPIN 1, VPIN 7, VPIN 9 = 0V; VPIN 2 = 1V		22	33		22	33	mA

ELECTRICAL CHARACTERISTICS: Unless otherwise stated, these specifications apply for , RT = 3.65k, CT = 1nF, Vcc = 15V, -55°C<Ta<125°C for the UC1825, -40°C<Ta<85°C for the UC2825, and 0°C<Ta<70°C for the UC3825, Ta=TJ.

* This parameter not 100% tested in production but guaranteed by design.

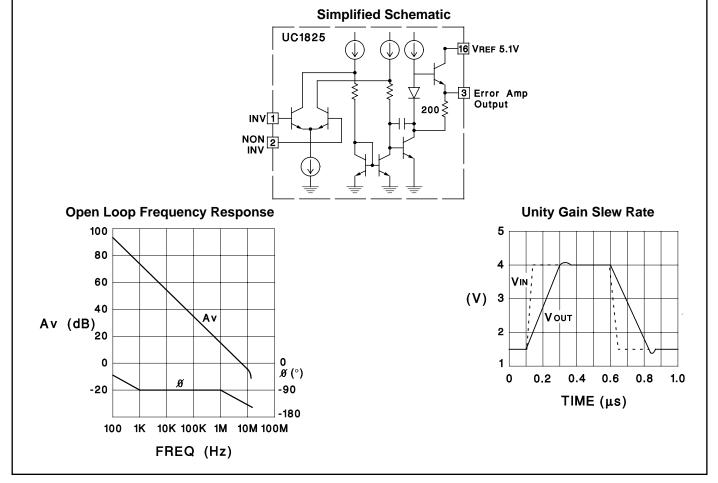
Printed Circuit Board Layout Considerations

UC1825 UC2825 UC3825

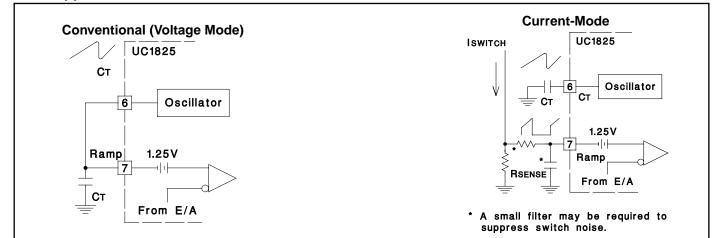
High speed circuits demand careful attention to layout and component placement. To assure proper performance of the UC1825 follow these rules: 1) Use a ground plane. 2) Damp or clamp parasitic inductive kick energy from the gate of driven MOSFETs. Do not allow the output pins to ring below ground. A series gate resistor or a shunt 1 Amp Schottky diode at the output pin will serve

this purpose. 3) Bypass Vcc, Vc, and VREF. Use 0.1μ F monolithic ceramic capacitors with low equivalent series inductance. Allow less than 1 cm of total lead length for each capacitor between the bypassed pin and the ground plane. 4) Treat the timing capacitor, CT, like a bypass capacitor.

Error Amplifier Circuit

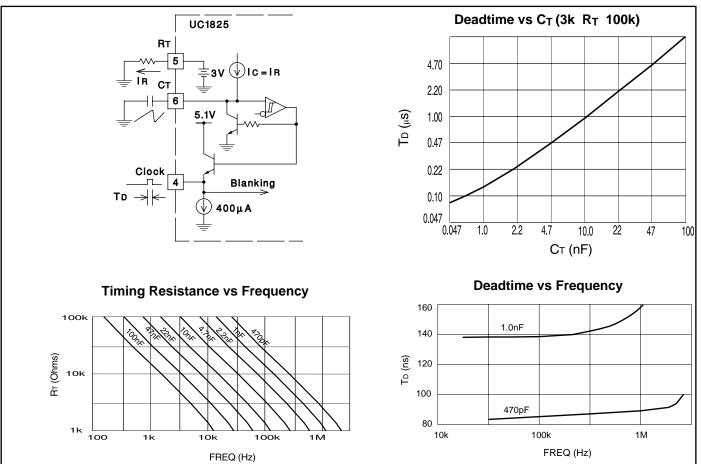


PWM Applications

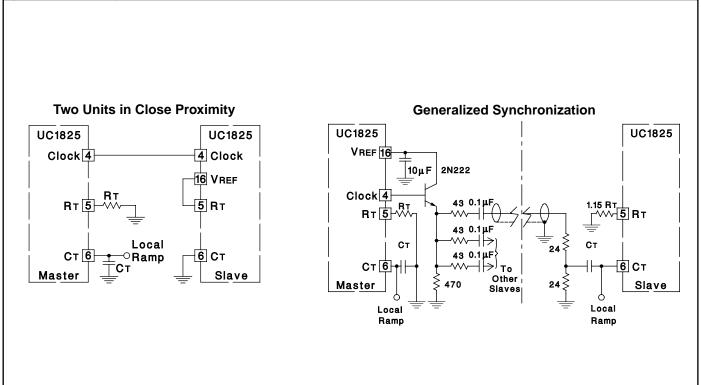


Oscillator Circuit

UC1825 UC2825 UC3825

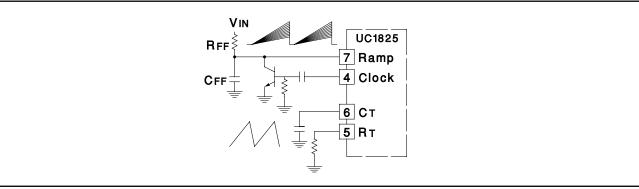


Synchronized Operation



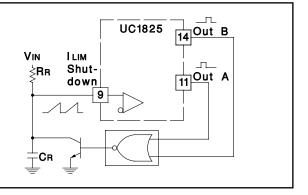
UC1825 UC2825 UC3825

Forward Technique for Off-Line Voltage Mode Application

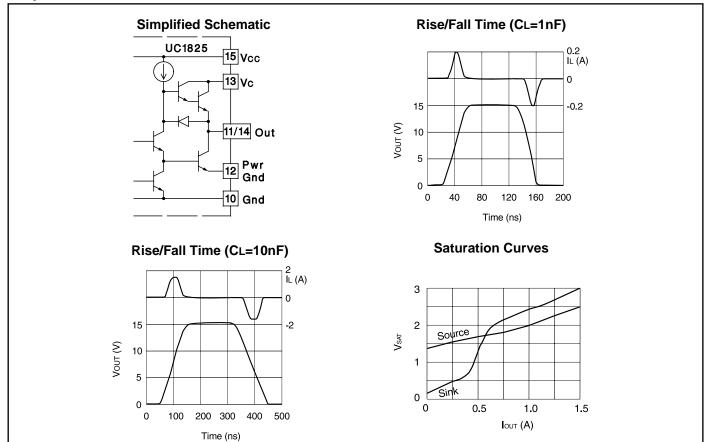


Constant Volt-Second Clamp Circuit

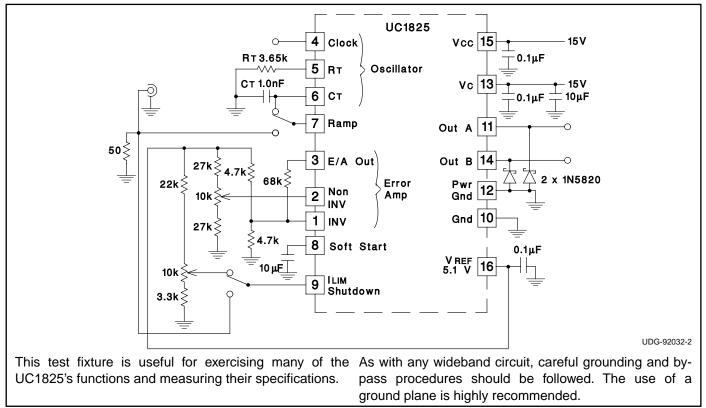
The circuit shown here will achieve a constant volt-second product clamp over varying input voltages. The ramp generator components, RT and CR are chosen so that the ramp at Pin 9 crosses the 1V threshold at the same time the desired maximum volt-second product is reached. The delay through the functional nor block must be such that the ramp capacitor can be completely discharged during the minimum deadtime.



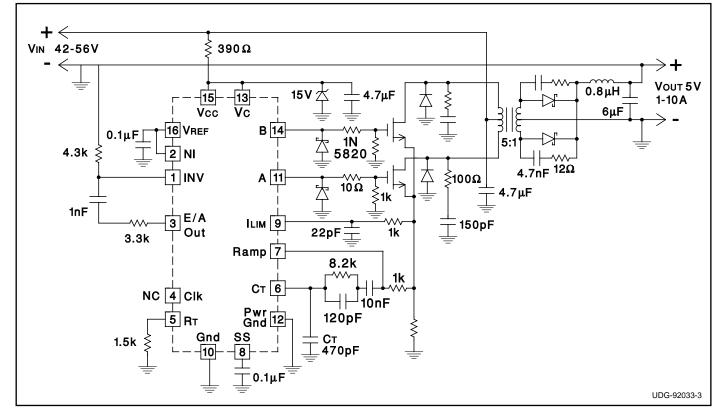
Output Section



Open Loop Laboratory Test Fixture



Design Example: 50W, 48V to 5V DC to DC Converter - 1.5MHz Clock Frequency





PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
5962-87681012A	ACTIVE	LCCC	FK	20	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962- 87681012A UC1825L/ 883B	Samples
5962-8768101EA	ACTIVE	CDIP	J	16	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-8768101EA UC1825J/883B	Samples
5962-8768101QFA	ACTIVE	CFP	W	16	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-8768101QF A UC1825W/883B	Samples
UC1825J	ACTIVE	CDIP	J	16	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	UC1825J	Samples
UC1825J883B	ACTIVE	CDIP	J	16	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-8768101EA UC1825J/883B	Samples
UC1825L	ACTIVE	LCCC	FK	20	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	UC1825L	Samples
UC1825L883B	ACTIVE	LCCC	FK	20	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962- 87681012A UC1825L/ 883B	Samples
UC1825W883B	ACTIVE	CFP	W	16	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-8768101QF A UC1825W/883B	Samples
UC2825DW	ACTIVE	SOIC	DW	16	40	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	UC2825DW	Samples
UC2825DWG4	ACTIVE	SOIC	DW	16	40	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	UC2825DW	Samples
UC2825DWTR	ACTIVE	SOIC	DW	16	2000	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	UC2825DW	Samples
UC2825J	ACTIVE	CDIP	J	16	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-40 to 85	UC2825J	Samples
UC2825N	ACTIVE	PDIP	Ν	16	25	RoHS & Green	NIPDAU	N / A for Pkg Type	-40 to 85	UC2825N	Samples
UC2825NG4	ACTIVE	PDIP	Ν	16	25	RoHS & Green	NIPDAU	N / A for Pkg Type	-40 to 85	UC2825N	Samples
UC3825DW	ACTIVE	SOIC	DW	16	40	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	0 to 70	UC3825DW	Samples

Orderable Device	Status	Package Type	-	Pins	-	Eco Plan	Lead finish/	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)	Ball material	(3)		(4/5)	
UC3825DWG4	ACTIVE	SOIC	DW	16	40	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	0 to 70	UC3825DW	Samples
UC3825DWTR	ACTIVE	SOIC	DW	16	2000	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	0 to 70	UC3825DW	Samples
UC3825N	ACTIVE	PDIP	N	16	25	RoHS & Green	NIPDAU	N / A for Pkg Type	0 to 70	UC3825N	Samples
UC3825NG4	ACTIVE	PDIP	N	16	25	RoHS & Green	NIPDAU	N / A for Pkg Type	0 to 70	UC3825N	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <= 1000ppm threshold. Antimony trioxide based flame retardants must also meet the <= 1000ppm threshold requirement.

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.



PACKAGE OPTION ADDENDUM

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

- OTHER QUALIFIED VERSIONS OF UC1825, UC2825, UC2825M, UC3825 :
- Catalog : UC3825, UC2825
- Military : UC2825M, UC1825
- Space : UC1825-SP

NOTE: Qualified Version Definitions:

- Catalog TI's standard catalog product
- Military QML certified for Military and Defense Applications
- Space Radiation tolerant, ceramic packaging and qualified for use in Space-based application

PACKAGE MATERIALS INFORMATION

Texas Instruments

www.ti.com

TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal												
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
UC2825DWTR	SOIC	DW	16	2000	330.0	16.4	10.75	10.7	2.7	12.0	16.0	Q1
UC3825DWTR	SOIC	DW	16	2000	330.0	16.4	10.75	10.7	2.7	12.0	16.0	Q1



www.ti.com

PACKAGE MATERIALS INFORMATION

10-Mar-2022



*All dimensions are nominal

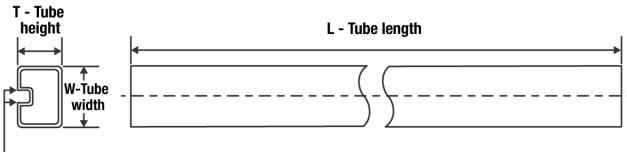
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
UC2825DWTR	SOIC	DW	16	2000	367.0	367.0	38.0
UC3825DWTR	SOIC	DW	16	2000	853.0	449.0	35.0



www.ti.com

10-Mar-2022

TUBE



B - Alignment groove width

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
Device	T ackage Marine	i ackage i ype	1 1113	01.64	E ()	•• ()	ι (μπ)	D (iiiii)
5962-8768101QFA	W	CFP	16	1	506.98	26.16	6220	NA
UC1825L	FK	LCCC	20	1	506.98	12.06	2030	NA
UC1825W883B	W	CFP	16	1	506.98	26.16	6220	NA
UC2825DW	DW	SOIC	16	40	507	12.83	5080	6.6
UC2825DWG4	DW	SOIC	16	40	507	12.83	5080	6.6
UC2825N	N	PDIP	16	25	506	13.97	11230	4.32
UC2825NG4	N	PDIP	16	25	506	13.97	11230	4.32
UC3825DW	DW	SOIC	16	40	507	12.83	5080	6.6
UC3825DWG4	DW	SOIC	16	40	507	12.83	5080	6.6
UC3825N	N	PDIP	16	25	506	13.97	11230	4.32
UC3825NG4	N	PDIP	16	25	506	13.97	11230	4.32

LEADLESS CERAMIC CHIP CARRIER

FK (S-CQCC-N**) 28 TERMINAL SHOWN



NOTES: A. All linear dimensions are in inches (millimeters).

B. This drawing is subject to change without notice.

- C. This package can be hermetically sealed with a metal lid.
- D. Falls within JEDEC MS-004



DW 16

GENERIC PACKAGE VIEW

SOIC - 2.65 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT

7.5 x 10.3, 1.27 mm pitch

This image is a representation of the package family, actual package may vary. Refer to the product data sheet for package details.





DW0016A



PACKAGE OUTLINE

SOIC - 2.65 mm max height

SOIC



NOTES:

- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
 This drawing is subject to change without notice.
 This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm, per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm, per side.
- 5. Reference JEDEC registration MS-013.



DW0016A

EXAMPLE BOARD LAYOUT

SOIC - 2.65 mm max height

SOIC



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



DW0016A

EXAMPLE STENCIL DESIGN

SOIC - 2.65 mm max height

SOIC



NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

9. Board assembly site may have different recommendations for stencil design.



W (R-GDFP-F16)

CERAMIC DUAL FLATPACK



- NOTES: A. All linear dimensions are in inches (millimeters).
 - B. This drawing is subject to change without notice.
 - C. This package can be hermetically sealed with a ceramic lid using glass frit.
 - D. Index point is provided on cap for terminal identification only.
 - E. Falls within MIL STD 1835 GDFP2-F16



J (R-GDIP-T**) 14 LEADS SHOWN

CERAMIC DUAL IN-LINE PACKAGE



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



NOTES:

- A. All linear dimensions are in inches (millimeters).B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- \triangle The 20 pin end lead shoulder width is a vendor option, either half or full width.



IMPORTANT NOTICE AND DISCLAIMER

TI PROVIDES TECHNICAL AND RELIABILITY DATA (INCLUDING DATA SHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES "AS IS" AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS AND IMPLIED, INCLUDING WITHOUT LIMITATION ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for skilled developers designing with TI products. You are solely responsible for (1) selecting the appropriate TI products for your application, (2) designing, validating and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, regulatory or other requirements.

These resources are subject to change without notice. TI grants you permission to use these resources only for development of an application that uses the TI products described in the resource. Other reproduction and display of these resources is prohibited. No license is granted to any other TI intellectual property right or to any third party intellectual property right. TI disclaims responsibility for, and you will fully indemnify TI and its representatives against, any claims, damages, costs, losses, and liabilities arising out of your use of these resources.

TI's products are provided subject to TI's Terms of Sale or other applicable terms available either on ti.com or provided in conjunction with such TI products. TI's provision of these resources does not expand or otherwise alter TI's applicable warranties or warranty disclaimers for TI products.

TI objects to and rejects any additional or different terms you may have proposed.

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265 Copyright © 2022, Texas Instruments Incorporated